

Features

- 1200-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives







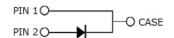
Part Number	Package	Qty(PCS)	
STPSC2H12B2Y-TR	TO-252-2L	2500	

Maximum Ratings ($T_c = 25 \, ^{\circ}C$ unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions
V _{RRM}	Repetitive Peak Reverse Voltage	1200	V	
V _{RSM}	Surge Peak Reverse Voltage	1200	V	
I _F	Continuous Forward Current	9 4.3 2	А	T _c =25°C T _c =135°C T _c =164°C
I _{FRM}	Repetitive Peak Forward Surge Current	10	А	T _c =25°C, t _p = 10 ms, Half Sine Wave
I _{FSM}	Non-Repetitive Peak Forward Surge Current	30	А	T_c =25°C, t_p = 10 ms, Half Sine Wave
P _{tot}	Power Dissipation	48 21	W	T _c =25°C T _c =110°C
T_{J} , T_{stg}	Operating Junction and Storage Temperature	-55 to +175	°C	
∫i²dt	i²dt value	4.5	A ² s	T _c =25°C, t _p = 10 ms, Half Sine Wave



TO-252-2L





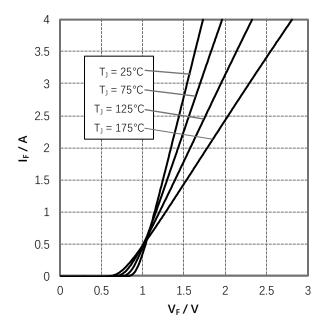
Electrical Characteristics

Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Conditions
V _{DC}	DC Blocking Voltage	1200			V	
V _F	Forward Voltage		1.36 1.78	1.7 2.5	V	I _F = 2 A T _J =25°C I _F = 2 A T _J =175°C
I _R	Reverse Current		1.2 7.6	50 100	μΑ	V _R = 1200 V T _J =25°C V _R = 1200 V T _J =175°C
Q_c	Total Capacitive Charge		12		nC	V _R = 800 V T _J = 25°C
С	Total Capacitance		177 12 10		pF	V _R = 0 V, T _J = 25°C, f = 1 MHz V _R = 400 V, T _J = 25°C, f = 1 MHz V _R = 800 V, T _J = 25°C, f = 1 MHz
E _c	Capacitance Stored Energy		6		μJ	V _R = 800 V

Thermal Characteristics

Symbol	Parameter	Тур.	Unit
R _{eJC}	Thermal Resistance from Junction to Case	3.1	°C/W

Typical Performance





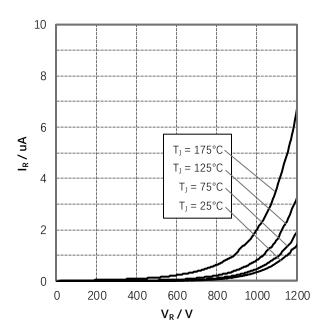


Figure 2. Reverse Characteristics

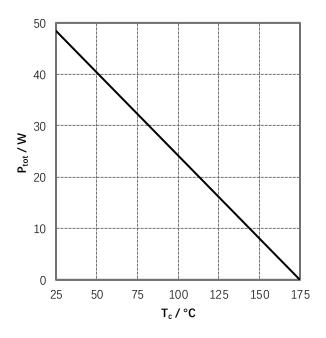


Figure 3. Power Derating

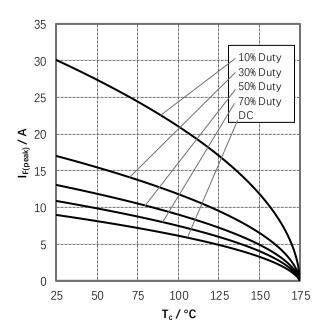


Figure 4. Current Derating

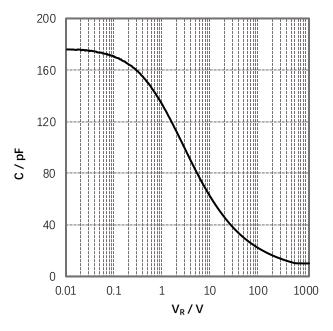


Figure 5. Capacitance vs. Reverse Voltage

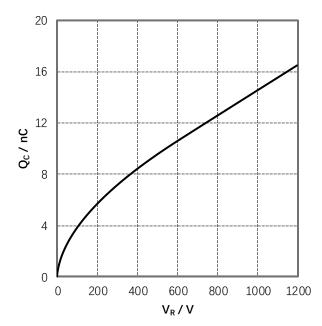
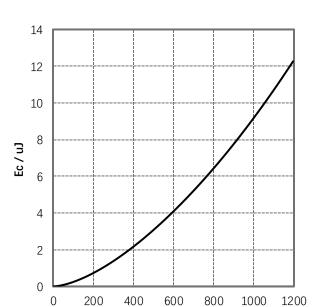


Figure 6. Total Capacitance Charge vs. Reverse Voltage



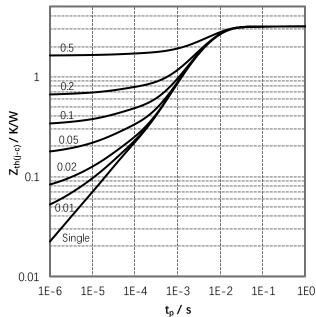


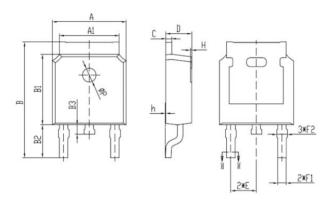
Figure 7. Capacitance Stored Energy

 V_R/V

Figure 8. Transient Thermal Impedance



Package Information TO-252-2L





项目	规范(mm)		
	MIN	MAX	
A	6.50	6.70	
A1	5.16	5.46	
В	9.77	10.17	
B1	6.00	6.20	
B2	2.60	3.00	
В3	0.70	0.90	
C	0.45	0.61	
D	2.20	2.40	
E	2.186	2.386	
F1	0.67	0.87	
F2	0.76	0.96	
Н	0.00	0.30	
h	0.00	0.127	
L	6.50	6.70	
фP	1.10	1.30	

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